

COMBINED DECLARATION AND POWER OF ATTORNEY
FOR PATENT APPLICATION

As a below named inventor, I hereby declare that:

My residence, post office address and citizenship are as stated below next to my name.

I believe I am the original, first and sole inventor (if only one name is listed below) or an original, first and joint inventor (if plural names are listed below) of the subject matter which is claimed and for which a patent is sought on the invention entitled **METHOD OF FORMING A GATE ELECTRODE, METHOD OF MANUFACTURING A SEMICONDUCTOR DEVICE HAVING THE GATE ELECTRODE, AND METHOD OF OXIDIZING A SUBSTRATE** the specification of which:

☒ is attached hereto.

I hereby state that I have reviewed and understand the contents of the above-identified specification, including the claims, as amended by any amendment referred to above.

I acknowledge the duty to disclose information which is material to the patentability of this application in accordance with Title 37, Code of Federal Regulations, Sec. 1.56.

I hereby claim foreign priority benefits under Title 35, United States Code, Sec. 119 (a)-(d) or §365(b) of any foreign application(s) for patent or inventor's certificate, or §365(a) of any PCT international application which designated at least one country other than the United States of America, listed below and have also identified below any foreign application for patent or inventor's certificate, or of any PCT international application having a filing date before that of the application on which priority is claimed:

Prior Foreign Application(s)

2002-66804
(Number)

Republic of Korea
(Country)

31 October 2002
(Day/Month/Year Filed)

Claiming
Priority?
☒ Yes ☐ No

I hereby claim the benefit under Title 35, United States Code, Sec. 119(e) of any United States provisional application listed below:

Provisional Application No.

Filing Date

I hereby claim the benefit under Title 35, United States Code, Sec. 120 or §365(c) of any PCT international application designating the United States of America listed below and,

these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issued thereon.

Full name of sole or first inventor: Jae-Jong HAN

Inventor's signature: Jae-Jong HAN

16 September 2003
(Date)

Residence: Seoul, Republic of Korea

Citizenship: Republic of Korea

Post Office address: 323-1004, 11th Complex, New Banpo Apt. 58-24
Jamwon-dong, Seocho-gu
Seoul, Republic of Korea

Full name of second joint inventor: Yong-Woo HYUNG

Inventor's signature: Yong-Woo HYUNG

16 September 2003
(Date)

Residence: Gyeonggi-do, Republic of Korea

Citizenship: Republic of Korea

Post Office address: 523-1605, 5th Complex, Samsung Apt.
Suji-eup, Yongin-city
Gyeonggi-do, Republic of Korea

Full name of third joint inventor: Seung-Mok SHIN

Inventor's signature: Seung-Mok SHIN

16 September 2003
(Date)

Residence: Gyeonggi-do, Republic of Korea

Citizenship: Republic of Korea

Post Office address: 501-303 Shinnamusil Jukong Apt.
Yongtong-dong, Paldal-gu, Suwon-city
Gyeonggi-do, Republic of Korea

Full name of fourth joint inventor: Kong-Soo LEE

Inventor's signature: Kang-Soo Lee

16 September 2003
(Date)

Residence: Gyeonggi-do, Republic of Korea

Citizenship: Republic of Korea

Post Office address: 104-1305 Hanshin Apt.
Byungjum-ri, Taeon-eup, Hwasung-gun
Gyeonggi-do, Republic of Korea

Full name of fifth joint inventor: Eun-Jung YUN

Inventor's signature: Eun-Jung YUN

18 September 2003
(Date)

Residence: Seoul, Republic of Korea

Citizenship: Republic of Korea

Post Office address: 204 Hanvit Bldg., 2-34 Yangjae 1-dong
Seocho-gu
Seoul, Republic of Korea